



STPS1L30A/U

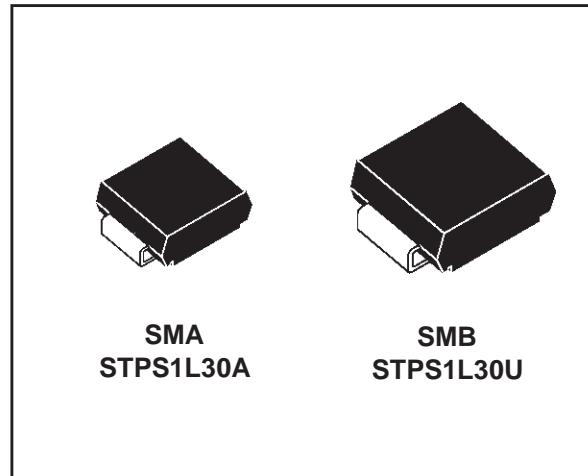
LOW DROP POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

| | |
|----------------------|--------|
| I _{F(AV)} | 1 A |
| V _{RRM} | 30 V |
| T _j (max) | 150 °C |
| V _F (max) | 0.3 V |

FEATURES AND BENEFITS

- VERY LOW FORWARD VOLTAGE DROP FOR LESS POWER DISSIPATION
- OPTIMIZED CONDUCTION/REVERSE LOSSES TRADE-OFF WHICH MEANS THE HIGHEST YIELD IN THE APPLICATIONS
- SURFACE MOUNT MINIATURE PACKAGE



DESCRIPTION

Single Schottky rectifier suited to Switched Mode Power Supplies and high frequency DC to DC converters, freewheel diode and integrated circuit latch up protection.

Packaged in SMA and SMB, this device is especially intended for use in parallel with MOSFETs in synchronous rectification.

ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter | | Value | Unit |
|---------------------|--|--------------------------------|---------------|------|
| V _{RRM} | Repetitive peak reverse voltage | | 30 | V |
| I _{F(RMS)} | RMS forward current | | 10 | A |
| I _{F(AV)} | Average forward current | T _L = 135°C δ = 0.5 | 1 | A |
| I _{FSM} | Surge non repetitive forward current | tp = 10 ms Sinusoidal | 75 | A |
| I _{RRM} | Repetitive peak reverse current | tp = 2 μs F = 1kHz square | 1 | A |
| I _{RSR} | Non repetitive peak reverse current | tp = 100 μs square | 1 | A |
| T _{stg} | Storage temperature range | | - 65 to + 150 | °C |
| T _j | Maximum operating junction temperature * | | 150 | °C |
| dV/dt | Critical rate of rise of reverse voltage | | 10000 | V/μs |

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit |
|-----------------------|------------------|-----|-------|------|
| R _{th} (j-l) | Junction to lead | SMA | 30 | °C/W |
| | | SMB | 25 | |

STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Parameters | Tests Conditions | Min. | Typ. | Max. | Unit | |
|------------------|-------------------------|------------------------|-----------------------------------|-------|-------|-------|----|
| I _R * | Reverse leakage Current | T _j = 25°C | V _R = V _{RRM} | | | 200 | μA |
| | | T _j = 100°C | | 6 | 15 | mA | |
| V _F * | Forward Voltage drop | T _j = 25°C | I _F = 1 A | | | 0.395 | V |
| | | T _j = 125°C | | 0.26 | 0.3 | | |
| | | T _j = 25°C | I _F = 2 A | | | 0.445 | |
| | | T _j = 125°C | | 0.325 | 0.375 | | |

Pulse test : * tp = 380 μs, δ < 2%

To evaluate the maximum conduction losses use the following equation :

$$P = 0.225 \times I_{F(AV)} + 0.075 I_{F}^2(\text{RMS})$$

Fig. 1: Average forward power dissipation versus average forward current.

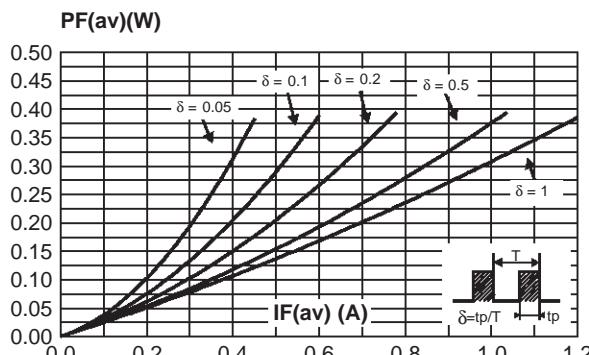


Fig. 3-1: Non repetitive surge peak forward current versus overload duration (maximum values) (SMB).

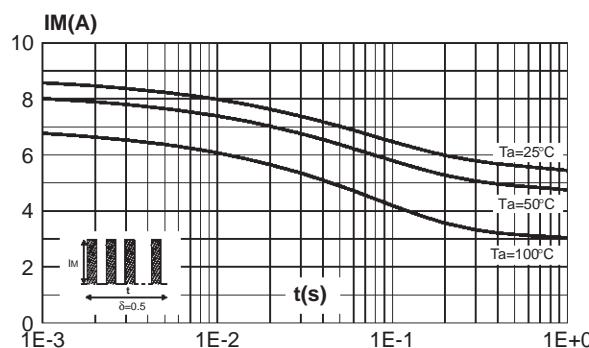


Fig. 2: Average forward current versus ambient temperature (δ=0.5).

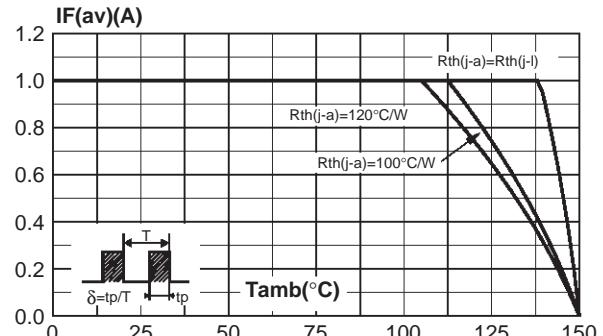


Fig. 3-2: Non repetitive surge peak forward current versus overload duration (maximum values) (SMA).

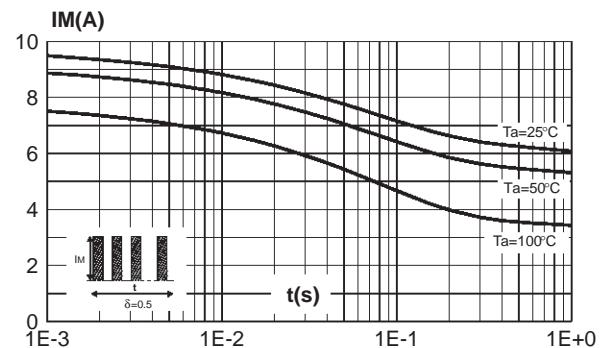


Fig. 4-1: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, $e(Cu)=35\mu m$, recommended pad layout) (SMB).

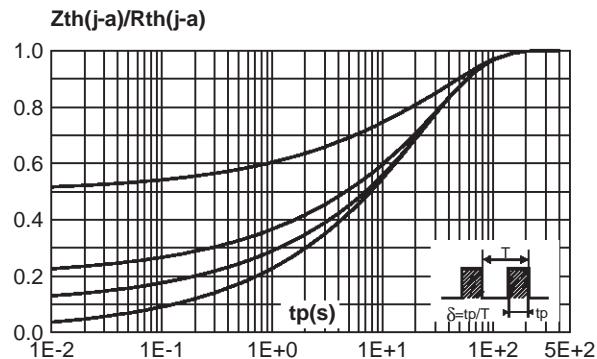


Fig. 4-2: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, $e(Cu)=35\mu m$, recommended pad layout) (SMA).

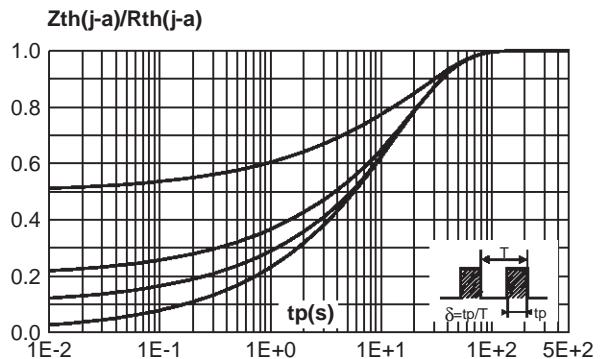


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values).

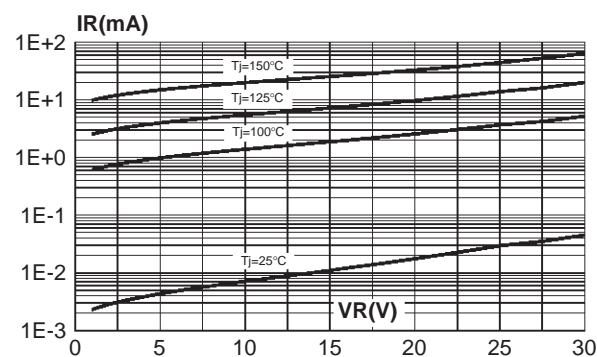


Fig. 6: Junction capacitance versus reverse voltage applied (typical values).

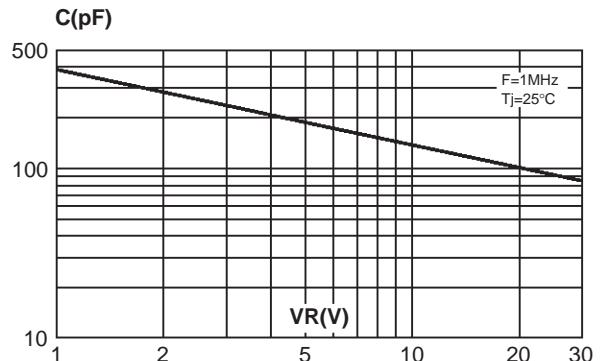


Fig. 7-1: Forward voltage drop versus forward current (typical values, high level).

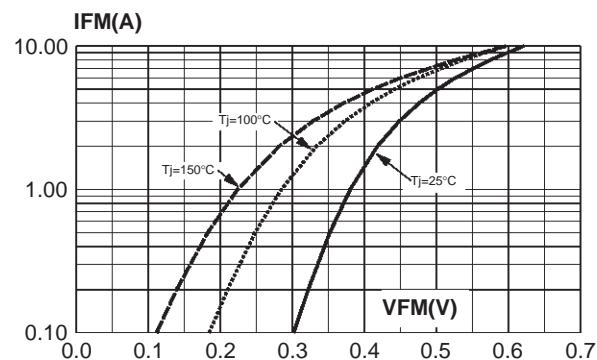
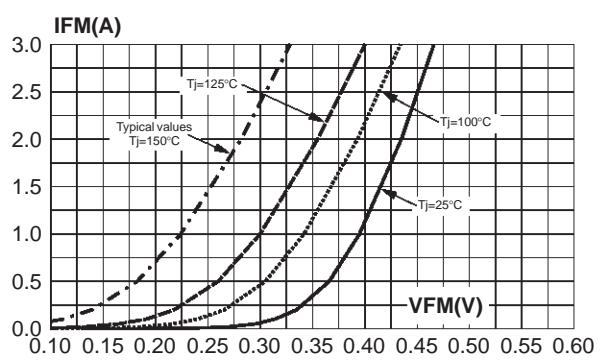


Fig. 7-2: Forward voltage drop versus forward current (maximum values, low level).



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Fig. 8-1: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35 μ m) (SMB).

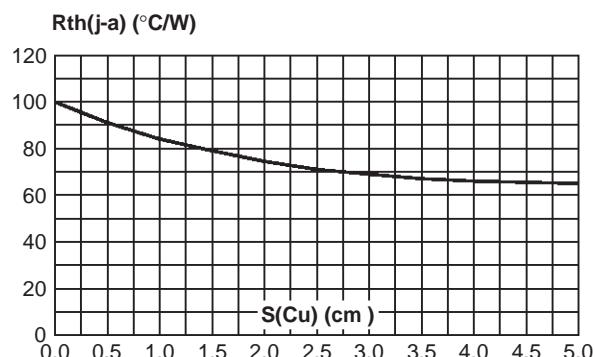
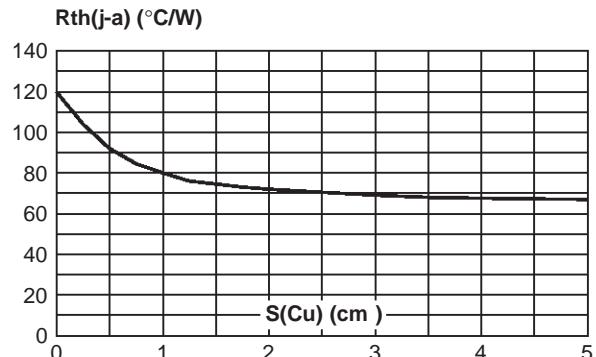


Fig. 8-2: Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness: 35 μ m) (SMA).

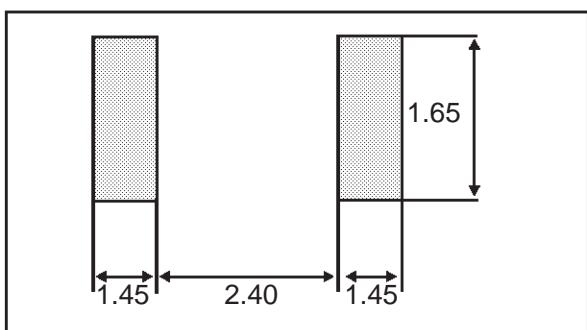


PACKAGE MECHANICAL DATA

SMA

| REF. | DIMENSIONS | | | |
|------|-------------|------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A1 | 1.90 | 2.70 | 0.075 | 0.106 |
| A2 | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 1.25 | 1.65 | 0.049 | 0.065 |
| c | 0.15 | 0.41 | 0.006 | 0.016 |
| E | 4.80 | 5.60 | 0.189 | 0.220 |
| E1 | 3.95 | 4.60 | 0.156 | 0.181 |
| D | 2.25 | 2.95 | 0.089 | 0.116 |
| L | 0.75 | 1.60 | 0.030 | 0.063 |

FOOT PRINT DIMENSIONS (in millimeters)

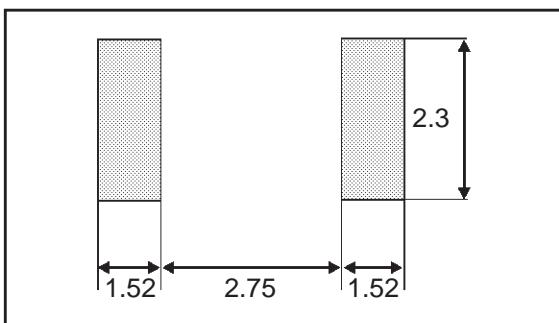


PACKAGE MECHANICAL DATA

SMB

| REF. | DIMENSIONS | | | |
|------|-------------|------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A1 | 1.90 | 2.45 | 0.075 | 0.096 |
| A2 | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 1.95 | 2.20 | 0.077 | 0.087 |
| c | 0.15 | 0.41 | 0.006 | 0.016 |
| E | 5.10 | 5.60 | 0.201 | 0.220 |
| E1 | 4.05 | 4.60 | 0.159 | 0.181 |
| D | 3.30 | 3.95 | 0.130 | 0.156 |
| L | 0.75 | 1.60 | 0.030 | 0.063 |

FOOT PRINT DIMENSIONS (in millimeters)



| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|---------|---------|--------|----------|---------------|
| STPS1L30U | G23 | SMB | 0.107g | 2500 | Tape & reel |
| STPS1L30A | GB3 | SMA | 0.068g | 5000 | Tape & reel |

- Band indicates cathode
- Epoxy meets UL94,V0

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